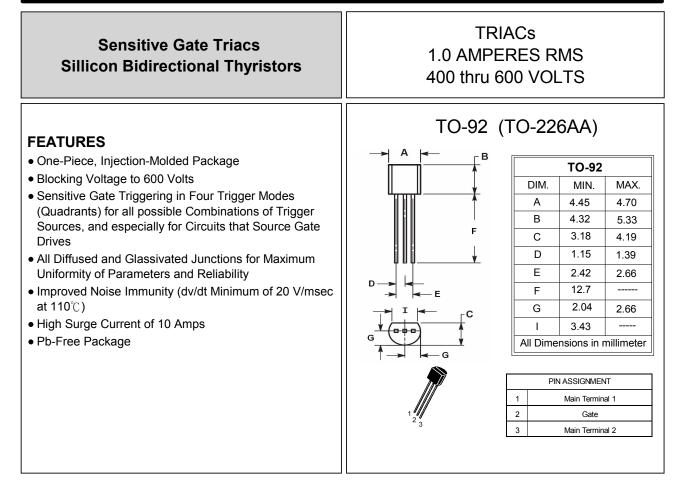
# LITE ON SEMICONDUCTOR

## **T1M3F-A SERIES**



### MAXIMUM RATINGS (Tj= 25°C unless otherwise noticed)

Rating	Symbol	Value	Unit
Peak Repetitive Off– State Voltage (TJ= -40 to 110°C, Sine Wave, 50 to 60 Hz; Gate Open)			
T1M3F400A T1M3F600A	Vdrm, Vrrm	400 600	Volts
On-State RMS Current Full Cycle Sine Wave 50 to 60 Hz (Tc = 50℃)		1.0	Amp
Peak Non-Repetitive Surge Current Full Cycle Sine Wave 60 Hz (Tj =25℃)	Ітѕм	10.0	Amps
Circuit Fusing Consideration (t = 8.3 ms)	l <sup>2</sup> t	0.60	A <sup>2</sup> s
Peak Gate Power ( $t \leq$ 2.0us ,Tc = 80 $^\circ \!\! C)$	Рдм	5.0	Watt
Average Gate Power (Tc = 80 $^\circ\!\mathbb{C},t\leq$ 8.3 ms )	PG(AV)	0.1	Watt
Peak Gate Current ( $t \leq 2.0 \text{us}$ ,Tc = 80 $^\circ \text{C}$ )	lgм	1.0	Amp
Peak Gate Voltage ( t $\leq$ 2.0us ,Tc = 80°C)	Vgм	5.0	Volts
Operating Junction Temperature Range	TJ	-40 to +110	°C
Storage Temperature Range	Tstg	-40 to +150	°C
Notice: (1) VDRM and VRRM for all types can be applied on a continuous basis. Blocking	RE	V. 3, Oct-2010, K	TXD13

voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance - Junction to Lead - Junction to Case - Junction to Ambient	RthJL RthJC RthJA	60 75 150	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8 from Case for 10 Seconds	TL	260	°C

#### ELECTRICAL CHARACTERISTICS (Tj=25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					•
Peak Reptitive Forward or Reverse Blocking CurrentTj =25 $^{\circ}$ C(VD=Rated VDRM and VRRM; Gate OPen)Tj =110 $^{\circ}$ C	Idrm Irrm			10 100	uA uA
ON CHARACTERISTICS					
Peak Forward On-State Voltage (ITM=± 1A Peak @Tp $\leq$ 2.0 ms, Duty Cycle $\leq$ 2%)	Vтм			1.9	Volts
Gate Trigger Current (V <sub>D</sub> = 12 Vdc; R <sub>L</sub> = 100 Ohms)	IGT1 IGT2 IGT3 IGT4	  	  	3.0 3.0 3.0 5.0	mA
Holding Current (VD = 12 V, Initiating Current = ± 200 mA, Gate Open)	lн		1.5	10	mA
Turn-On Time (VD = Rated VDRM , ITM = 1.0 A pk, IG = 25 mA)	tgt		2		us
Gate Trigger Voltage (V <sub>D</sub> = 12 Vdc; R <sub>L</sub> =100 Ohms)	VGT1 VGT2 VGT3 VGT4	  	0.66 0.77 0.84 0.88	2.0 2.0 2.0 2.5	Volts
Latching Current (VD=12V,IG= 10 mA)	IL1 IL2 IL3 IL4	  	1.6 10.5 1.5 2.5	15 20 15 15	mA
Gate Non-Trigger Voltage (VD= 12V, RL= 100 Ohms , TJ=110 $^\circ \!$	Vgd	0.1			Volts

### **DYNAMIC CHARACTERISTICS**

Critical Rate of Rise of Off-State Voltage (VD=Rated VDRM,Exponential Waveform, Gate Open, TJ=110℃)	dv/dt	20	60	 V/us	
					1

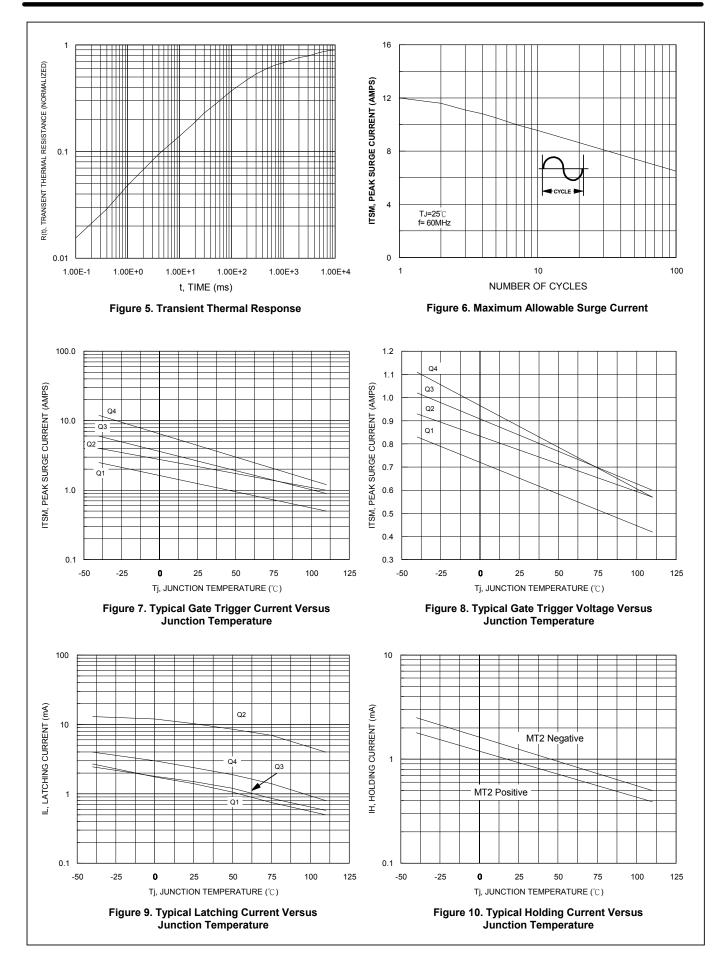
## RATING AND CHARACTERISTIC CURVES T1M3F-A SERIES

#### 1.2 0.8 IT(RMS), RMS ON-STATE CURRENT(AMPS) IT(RMS), RMS ON-STATE CURRENT(AMPS) 0.7 1.0 0.6 0.8 0.5 0.4 0.6 0.3 0.4 0.2 0.2 0.1 0.0 0.0 0 100 125 0 100 125 25 50 75 25 50 75 Ta, AMBIENT TEMPERATURE(°C) Tc, CASE TEMPERATURE(℃) Figure 1. RMS Current Deratiing Versus Figure 2. RMS Current Deratiing Versus Case Temperature Ambient Temperature 1.2 10 1.0 P(AV), POWER PISSIPATION (WATTS) 0.8 tpy. ITM, INSTANTANEOUS ON-STATE CURRENT (AMP) 1 max. 0.6 1 0.4 0.2 Ĩ . 0.0 0.1 0.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 IT(RMS), RMS ON-STATE CURRENT (AMPS) I Figure 3. Power Dissipation 1 1 0.01 0.4 0.8 1.2 2.4 2.8 1.6 2.0 VTM, INSTANTANEOUS ON-STATE VOLTAGE (VOLTS) Figure 4. On-State Characteristics

## **LITE ON**

## RATING AND CHARACTERISTIC CURVES T1M3F-A SERIES

# **LITE ON**





## **Important Notice and Disclaimer**

LSC reserves the right to make changes to this document and its products and specifications at any time without notice. Customers should obtain and confirm the latest product information and specifications before final design, purchase or use.

LSC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does LSC assume any liability for application assistance or customer product design. LSC does not warrant or accept any liability with products which are purchased or used for any unintended or unauthorized application.

No license is granted by implication or otherwise under any intellectual property rights of LSC.

LSC products are not authorized for use as critical components in life support devices or systems without express written approval of LSC.